

View Online at <https://aerobasegroup.com/nsn/5962-01-408-2912>

Maximum Power Dissipation Rating:

481.0 milliwatts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Bipolar and tested to mil-std-883 and 3-state output

Inclosure Material:

Ceramic

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Complementary-metal oxide-semiconductor logic

Design Function And Quantity:

4 gate, buffer

Case Outline Source And Designator:

D-1 mil-m-38510

Terminal Surface Treatment:

Tin

Product Name:

Bipolar cmos, quadruple bus buffer gates w/3-state outputs

Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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